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# QED223 Plastic Infrared Light Emitting Diode

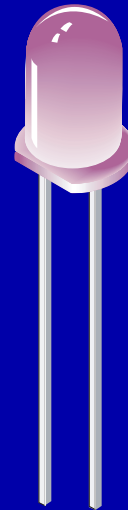
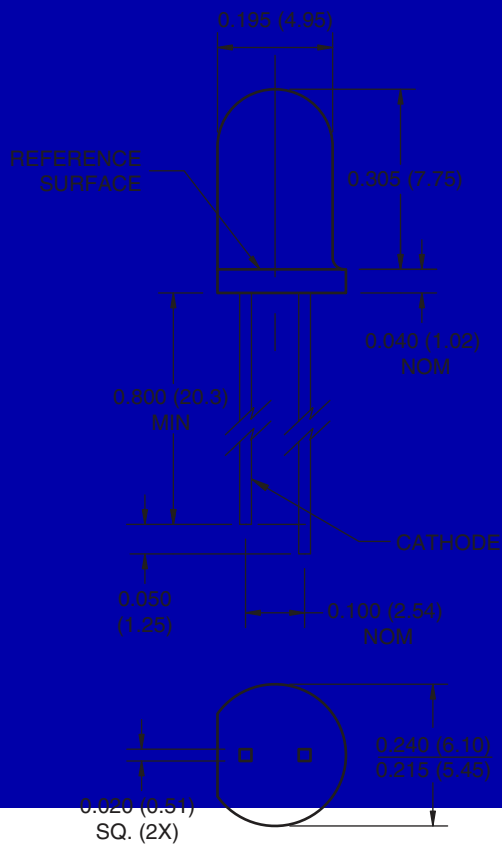
## Features

- $\lambda = 880\text{nm}$
- Chip material = AlGaAs
- Package type: T-1 3/4 (5mm lens diameter)
- Matched photosensor: QSD123/QSD124
- Medium wide emission angle,  $30^\circ$
- High output power
- Package material and color: clear, purple tinted, plastic

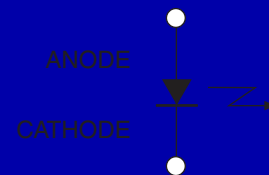
## Description

The QED223 is 880nm AlGaAs LEDs encapsulated in a clear purple tinted, plastic T-1 3/4 package.

## Package Dimensions



## Schematic



### Notes:

1. Dimensions of all drawings are in inches (mm).
2. Tolerance is  $\pm 0.010$  (0.25) on all non-nominal dimensions unless otherwise specified.

### Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating	Units
$T_{OPR}$	Operating Temperature	-40 to +100	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	-40 to +100	$^\circ\text{C}$
$T_{SOL-I}$	Soldering Temperature (Iron) <sup>(2)(3)(4)</sup>	240 for 5 sec	$^\circ\text{C}$
$T_{SOL-F}$	Soldering Temperature (Flow) <sup>(2)(3)</sup>	260 for 10 sec	$^\circ\text{C}$
$I_F$	Continuous Forward Current	100	mA
$V_R$	Reverse Voltage	5	V
$P_D$	Power Dissipation <sup>(1)</sup>	200	mW
$I_{F(Peak)}$	Peak Forward Current <sup>(5)</sup>	1.5	A

**Notes:**

- Derate power dissipation linearly 2.67mW/ $^\circ\text{C}$  above 25 $^\circ\text{C}$ .
- RMA flux is recommended.
- Methanol or isopropyl alcohols are recommended as cleaning agents.
- Soldering iron 1/16" (1.6mm) minimum from housing.
- Pulse conditions;  $t_p = 100\mu\text{s}$ ,  $T = 10\text{ms}$ .

### Electrical / Optical Characteristics ( $T_A = 25^\circ\text{C}$ )

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$\lambda_{PE}$	Peak Emission Wavelength	$I_F = 20\text{mA}$		890		nm
$TC_\lambda$	Temperature Coefficient			0.2		nm/ $^\circ\text{C}$
$2\theta^{1/2}$	Emission Angle	$I_F = 100\text{mA}$		30		$^\circ$
$V_F$	Forward Voltage	$I_F = 100\text{mA}$ , $t_p = 20\text{ms}$			1.7	V
$TC_{VF}$	Temperature Coefficient			-6		mV/ $^\circ\text{C}$
$I_R$	Reverse Current	$V_R = 5\text{V}$			10	$\mu\text{A}$
$I_E$	Radiant Intensity	$I_F = 100\text{mA}$ , $t_p = 20\text{ms}$	25			mW/sr
$TC_{IE}$	Temperature Coefficient			-0.3		%/ $^\circ\text{C}$
$t_r$	Rise Time	$I_F = 100\text{mA}$		900		ns
$t_f$	Fall Time			800		ns
$C_j$	Junction Capacitance	$V_R = 0\text{V}$		11		pF

## Typical Performance Curves

Figure 1. Normalized Intensity vs. Wavelength

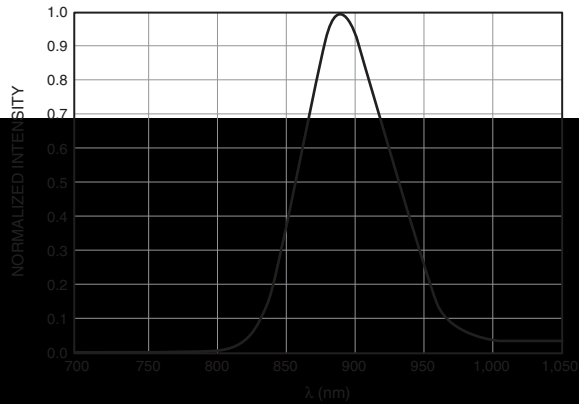


Figure 2. Peak Wavelength vs. Ambient Temperature

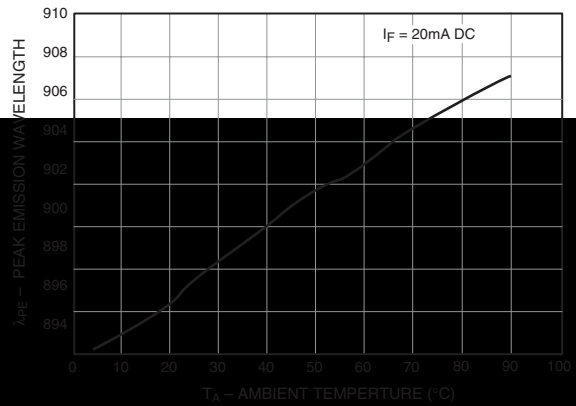


Figure 3. Normalized Radiant Intensity vs. Forward Current

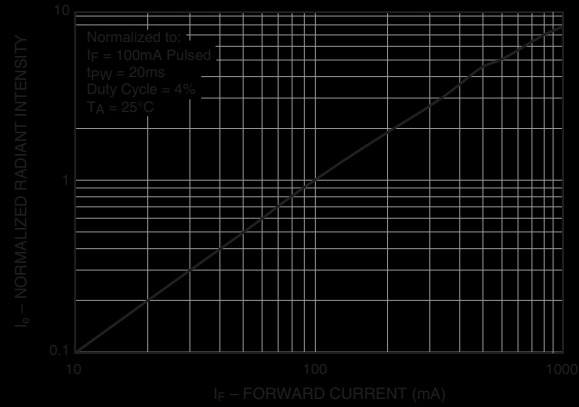


Figure 4. Normalized Radiant Intensity vs. Ambient Temperature

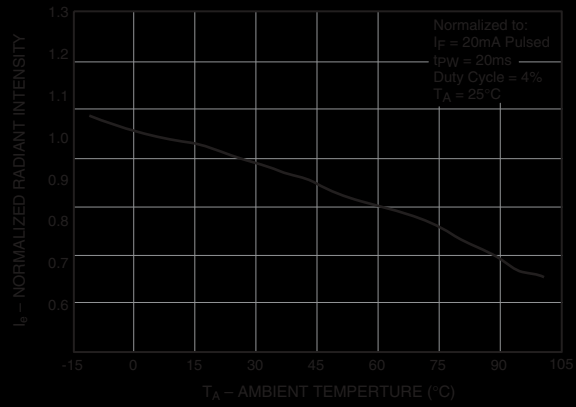


Figure 5. Forward Voltage vs. Forward Current

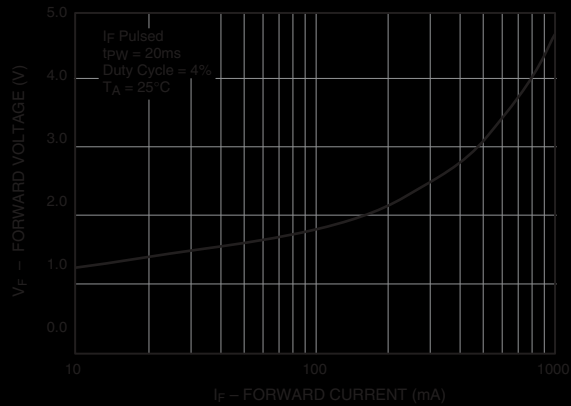
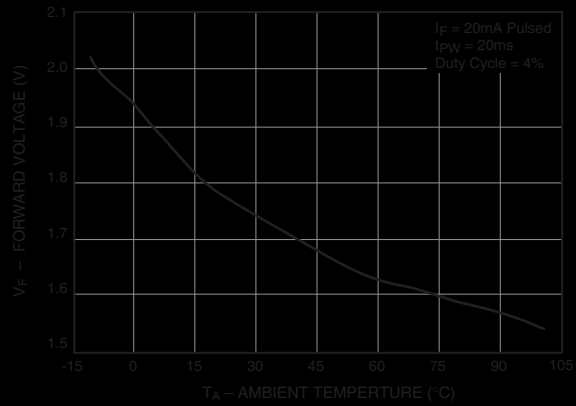


Figure 6. Forward Voltage vs. Ambient Temperature



Typical Performance Curves (Continued)

Figure 7. Radiation Diagram

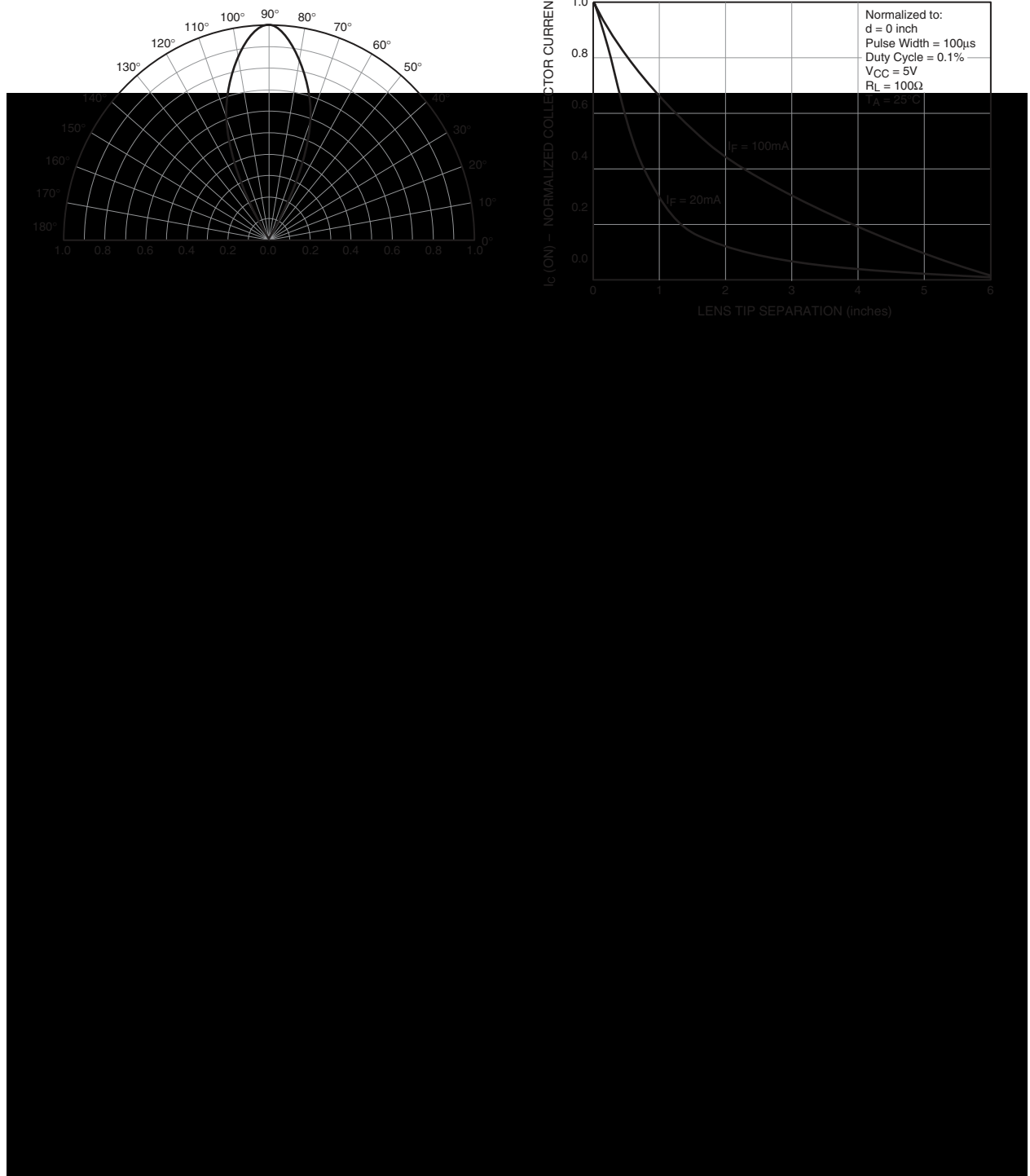
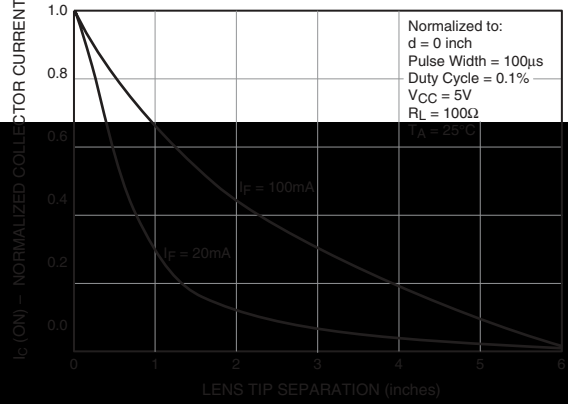


Figure 8. Coupling Characteristics of QED22X and QSD22X



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